

B0520WS~B0540WS

SCHOTTKY DIODES SCHOTTKY BARRIER DIODES

DESCRIPTION

The B0520WS~B0540WS are available in SOD-323 package

ORDERING INFORMATION

Package Type	Part Number				
SOD-323	B0520WS				
	B0530WS				
	B0540WS				
Note	SPQ:3,000pcs/Reel				
AiT provides all RoHS Compliant Products					

PIN DESCRIPTION



FEATURES

- Low Forward Voltage Drop
- Guard Ring Construction For Transient Protection.
- Negligible Reverse Recovery Time.
- Low Reverse Capacitance.
- Available in SOD-323 package

APPLICATIONS

Schotty barrier switching.

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ABSOLUTE MAXIMUM RATINGS

@ T_A=25°C, unless otherwise specified

Parameter	Symbol	B0520WS	B0530WS	B0540WS	Unit
Peak Repetitive Peak Reverse Voltage	V_{RR}				
Working Peak	V_{RWM}	20	30	40	V
DC Reverse Voltage	V_R				
RMS Reverse Voltage	V _{R(RMS)}	14	21	28	V
Forward Continuous Current	I _F		mA		
Repetitive Peak Forward Current @t≤1.0s	I _{FRM}		Α		
Power Dissipation	P _D		mW		
Thermal Resistance Junction to Ambient	R _{θJA}		°C/W		
Storage Temperature	Т _{STG}		°C		

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

@ T_A=25°C, unless otherwise specified

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Reverse Breakdown Voltage	V _{(BR)R}	I _R =10µA	B0520WS	20			
		I _R =10µA	B0530WS	30	-	-	V
		I _R =10μA	B0540WS	40			
Forward Voltage	\/-	I _F =20mA	mA			0.37	V
	VF	I _F =200mA		ı	-	0.60	V
Reverse Current	I _{RM}	V _R =10V	B0520WS	-	-		
		V _R =20V	B0530WS			5.0	μΑ
		V _R =30V	B0540WS				
Capacitance Between Terminals	Ст	V _R =0, f=1MHz		-	50	-	pF
Reverse Recovery Time t _{rr}	4	I _R =I _F =200mA,		-	10	-	ns
	l rr	I _{rr} =0.1 x I _R , R _L =100Ω					

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TYPICAL CHARACTERISTICS

@ T_A =25°C, unless otherwise specified

Figure 1. Typical Forward Characteristics

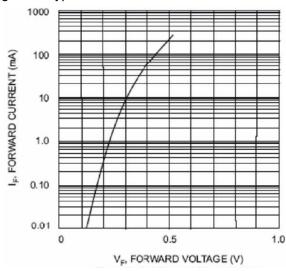
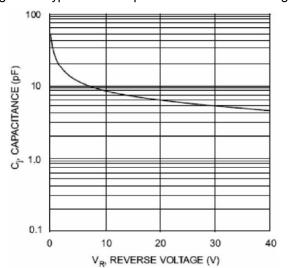
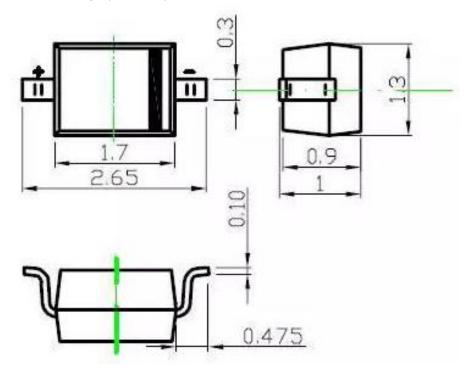


Figure 2. Typ. Junction Capacitance vs. Reverse Voltage



PACKAGE INFORMATION

Dimension in SOD-323 Package (Unit: mm)



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